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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Obsolete
Core Processor	80C51
Core Size	8-Bit
Speed	30/20MHz
Connectivity	UART/USART
Peripherals	POR
Number of I/O	32
Program Memory Size	8KB (8K × 8)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	44-QFP
Supplier Device Package	44-PQFP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/ts87c52x2-lcc

Email: info@E-XFL.COM

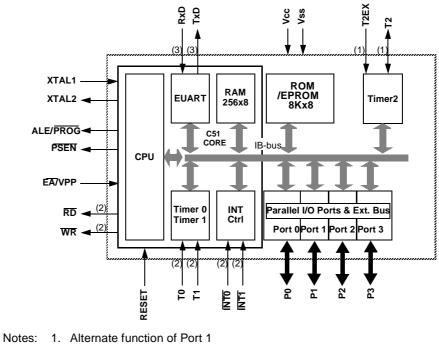
Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



Table 1. Memory Size

	ROM (bytes)	EPROM (bytes)	TOTAL RAM (bytes)	
TS80C32X2	0	0	256	
TS80C52X2	8k	0	256	
TS87C52X2	0	8k	256	

Block Diagram



2. Alternate function of Port 3

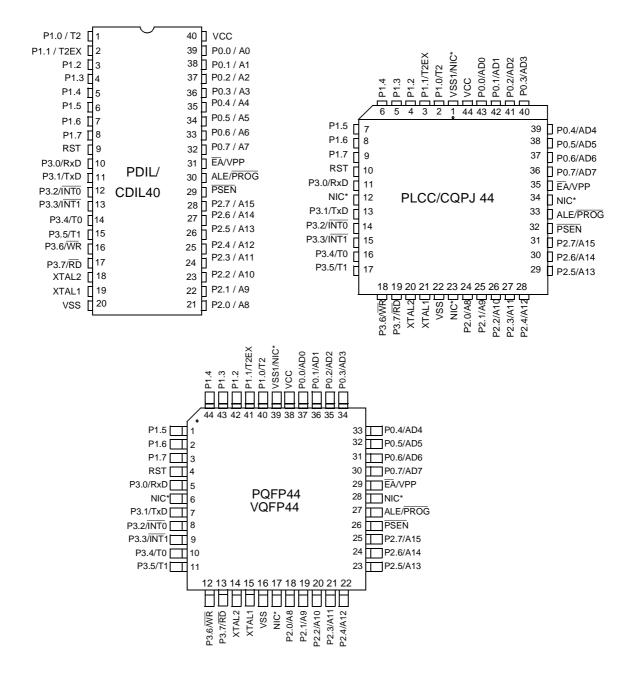
SFR Mapping

The Special Function Registers (SFRs) of the TS80C52X2 fall into the following categories:

- C51 core registers: ACC, B, DPH, DPL, PSW, SP, AUXR1
- I/O port registers: P0, P1, P2, P3
- Timer registers: T2CON, T2MOD, TCON, TH0, TH1, TH2, TMOD, TL0, TL1, TL2, RCAP2L, RCAP2H
- Serial I/O port registers: SADDR, SADEN, SBUF, SCON
- Power and clock control registers: PCON
- Interrupt system registers: IE, IP, IPH
- Others: AUXR, CKCON



Pin Configuration



*NIC: No Internal Connection



Mnemonic	I	Pin Nu	mber	Туре	Name and Function
	DIL	LCC	VQFP 1.4		
	13	15	9	I	INT1 (P3.3): External interrupt 1
	14	16	10	I	T0 (P3.4): Timer 0 external input
	15	17	11	I	T1 (P3.5): Timer 1 external input
	16	18	12	0	WR (P3.6): External data memory write strobe
	17	19	13	0	RD (P3.7): External data memory read strobe
Reset	9	10	4	I	Reset: A high on this pin for two machine cycles while the oscillator is running, resets the device. An internal diffused resistor to V_{SS} permits a power-on reset using only an external capacitor to V_{CC} .
ALE/PROG	30	33	27	O (I)	Address Latch Enable/Program Pulse: Output pulse for latching the low byte of the address during an access to external memory. In normal operation, ALE is emitted at a constant rate of 1/6 (1/3 in X2 mode) the oscillator frequency, and can be used for external timing or clocking. Note that one ALE pulse is skipped during each access to external data memory. This pin is also the program pulse input (PROG) during EPROM programming. ALE can be disabled by setting SFR's AUXR.0 bit. With this bit set, ALE will be inactive during internal fetches.
PSEN	29	32	26	0	Program Store ENable: The read strobe to external program memory. When executing code from the external program memory, <u>PSEN</u> is activated twice each machine cycle, except that two <u>PSEN</u> activations are skipped during each access to external data memory. <u>PSEN</u> is not activated during fetches from internal program memory.
ĒĀ/V _{PP}	31	35	29	I	External Access Enable/Programming Supply Voltage: EA must be externally held low to enable the device to fetch code from external program memory locations 0000H and 3FFFH (RB) or 7FFFH (RC), or FFFFH (RD). If EA is held high, the device executes from internal program memory unless the program counter contains an address greater than 3FFFH (RB) or 7FFFH (RC) EA must be held low for ROMless devices. This pin also receives the 12.75V programming supply voltage (V _{PP}) during EPROM programming. If security level 1 is programmed, EA will be internally latched on Reset.
XTAL1	19	21	15	I	Crystal 1: Input to the inverting oscillator amplifier and input
					to the internal clock generator circuits.
XTAL2	18	20	14	0	Crystal 2: Output from the inverting oscillator amplifier



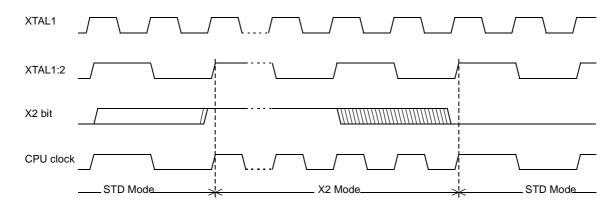


Figure 2. Mode Switching Waveforms

The X2 bit in the CKCON register (See Table 3.) allows to switch from 12 clock cycles per instruction to 6 clock cycles and vice versa. At reset, the standard speed is activated (STD mode). Setting this bit activates the X2 feature (X2 mode).

Note: In order to prevent any incorrect operation while operating in X2 mode, user must be aware that all peripherals using clock frequency as time reference (UART, timers) will have their time reference divided by two. For example a free running timer generating an interrupt every 20 ms will then generate an interrupt every 10 ms. UART with 4800 baud rate will have 9600 baud rate.

Table 3. CKCON Register

CKCON - Clock Control Register (8Fh)

7	6	5	4	3	2	1	0	
-	-	-	-	-	-	-	X2	
Bit Number	Bit Mnemonic	Description						
7	-	Reserved The value rea	ad from this b	it is indetermi	nate. Do not s	et this bit.		
6	-	Reserved The value rea	ad from this b	it is indetermi	nate. Do not s	et this bit.		
5	-	Reserved The value rea	ad from this b	it is indetermi	nate. Do not s	et this bit.		
4	-	Reserved The value rea	ad from this b	it is indetermi	nate. Do not s	et this bit.		
3	-	Reserved The value rea	ad from this b	it is indetermi	nate. Do not s	et this bit.		
2	-	Reserved The value rea	Reserved The value read from this bit is indeterminate. Do not set this bit.					
1	-	Reserved The value read from this bit is indeterminate. Do not set this bit.						
0	X2	Clear to sele	CPU and peripheral clock bit Clear to select 12 clock periods per machine cycle (STD mode, $F_{OSC}=F_{XTAL}/2$). Set to select 6 clock periods per machine cycle (X2 mode, $F_{OSC}=F_{XTAL}$).					

Reset Value = XXXX XXX0b

Not bit addressable

For further details on the X2 feature, please refer to ANM072 available on the web (http://www.atmel.com)





Dual Data Pointer Register (Ddptr)

The additional data pointer can be used to speed up code execution and reduce code size in a number of ways.

The dual DPTR structure is a way by which the chip will specify the address of an external data memory location. There are two 16-bit DPTR registers that address the external memory, and a single bit called

DPS = AUXR1/bit0 (See Table 5.) that allows the program code to switch between them (Refer to Figure 3).

Figure 3. Use of Dual Pointer

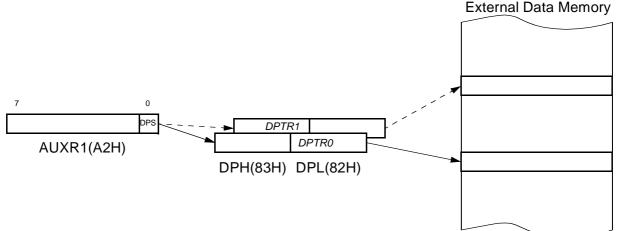


Table 4. AUXR1: Auxiliary Register 1

7	6	5	4	3	2	1	0		
-	-	-	-	GF3	0	-	DPS		
Bit Number	Bit Mnemonic	Description	Description						
7	-	Reserved The value re	ead from this	bit is indeterm	inate. Do not	set this bit.			
6	-	Reserved The value re	ead from this	bit is indeterm	inate. Do not	set this bit.			
5	-	Reserved The value re	ead from this	bit is indeterm	inate. Do not	set this bit.			
4	-	Reserved The value re	ead from this	bit is indeterm	inate. Do not	set this bit.			
3	GF3	This bit is a	general purp	ose user flag					
2	0	Reserved Always stud	Reserved Always stuck at 0						
1	-	Reserved The value re	Reserved The value read from this bit is indeterminate. Do not set this bit.						
0	DPS	Data Pointe Clear to select Set to select							

Reset Value = XXXX XXX0 Not bit addressable

Table 5	T2CON	Register
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T2CON - Timer 2 Control Register (C8h)

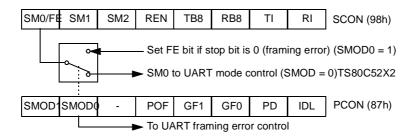
7	6	5	4	3	2	1	0	
TF2	EXF2	RCLK	TCLK	EXEN2	TR2	C/T2#	CP/RL2#	
Bit Number	Bit Mnemonic	Description						
7	TF2	Timer 2 overf Must be cleare Set by hardwa	d by software		CLK = 0 and T	CLK = 0.		
6	EXF2	Set when a ca EXEN2=1. When set, cau interrupt is ena Must be cleare	Timer 2 External Flag Set when a capture or a reload is caused by a negative transition on T2EX pin if					
5	RCLK	Receive Clock Clear to use time Set to use time	mer 1 overflov			•		
4	TCLK	Transmit Cloc Clear to use tin Set to use time	mer 1 overflov			•		
3	EXEN2	Timer 2 Exter Clear to ignore Set to cause a detected, if tim	e events on Ta capture or re	2EX pin for tim load when a n	egative transi		pin is	
2	TR2	Clear to turn o	Timer 2 Run control bit Clear to turn off timer 2. Set to turn on timer 2.					
1	C/T2#	Timer/Counter 2 select bit Clear for timer operation (input from internal clock system: F _{OSC}). Set for counter operation (input from T2 input pin, falling edge trigger). Must be 0 for clock out mode.						
0	CP/RL2#	Timer 2 Captu If RCLK=1 or 7 timer 2 overflo Clear to Auto-r EXEN2=1. Set to capture	CLK=1, CP/F w. eload on time	RL2# is ignored er 2 overflows o	or negative tra	ansitions on T2		

Reset Value = 0000 0000b Bit addressable



TS80C52X2 Serial I/O
PortThe serial I/O port in the TS80C52X2 is compatible with the serial I/O port in the 80C52.
It provides both synchronous and asynchronous communication modes. It operates as
an Universal Asynchronous Receiver and Transmitter (UART) in three full-duplex
modes (Modes 1, 2 and 3). Asynchronous transmission and reception can occur simul-
taneously and at different baud rates
Serial I/O port includes the following enhancements:
 Framing Error DetectionFraming bit error detection is provided for the three asynchronous modes (modes 1, 2
and 3). To enable the framing bit error detection feature, set SMOD0 bit in PCON regis-
ter (See Figure 6).

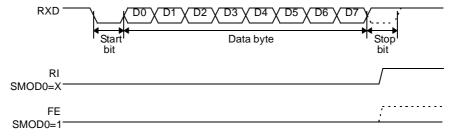
Figure 6. Framing Error Block Diagram



When this feature is enabled, the receiver checks each incoming data frame for a valid stop bit. An invalid stop bit may result from noise on the serial lines or from simultaneous transmission by two CPUs. If a valid stop bit is not found, the Framing Error bit (FE) in SCON register (See Table 9.) bit is set.

Software may examine FE bit after each reception to check for data errors. Once set, only software or a reset can clear FE bit. Subsequently received frames with valid stop bits cannot clear FE bit. When FE feature is enabled, RI rises on stop bit instead of the last data bit (See Figure 7. and Figure 8.).

Figure 7. UART Timings in Mode 1





1111 0000b).
For slave A, bit 1 is a 1; for slaves B and C, bit 1 is a don't care bit. To communicate with slaves B and C, but not slave A, the master must send an address with bits 0 and 1 both set (e.g. 1111 0011b).
To communicate with slaves A, B and C, the master must send an address with bit 0 set, bit 1 clear, and bit 2 clear (e.g. 1111 0001b).

Broadcast Address A broadcast address is formed from the logical OR of the SADDR and SADEN registers with zeros defined as don't-care bits, e.g.:

SADDR 0101 0110b SADEN 1111 1100b Broadcast =SADDR OR SADEN1111 111Xb

The use of don't-care bits provides flexibility in defining the broadcast address, however in most applications, a broadcast address is FFh. The following is an example of using broadcast addresses:

Slave A:SADDR1111 0001b <u>SADEN1111 1010b</u> Broadcast1111 1X11b, Slave B:SADDR1111 0011b <u>SADEN1111 1001b</u> Broadcast1111 1X11B,

Slave C:SADDR=1111 0010b <u>SADEN1111 1101b</u> Broadcast1111 1111b

For slaves A and B, bit 2 is a don't care bit; for slave C, bit 2 is set. To communicate with all of the slaves, the master must send an address FFh. To communicate with slaves A and B, but not slave C, the master can send and address FBh.

Reset AddressesOn reset, the SADDR and SADEN registers are initialized to 00h, i.e. the given and
broadcast addresses are XXXX XXXb (all don't-care bits). This ensures that the serial
port will reply to any address, and so, that it is backwards compatible with the 80C51
microcontrollers that do not support automatic address recognition.

 Table 7.
 SADEN Register

7	6	5	4	3	2	1	0
Decet Valu		0006			<u>.</u>		
Reset Valu		0000					
Not bit add	ressable						
Table 8 S		vietor					
	-						
	-		er (A9h)				
Table 8. S SADDR - S 7	-		er (A9h) 4	3	2	1	0
SADDR - S	lave Addre	ess Registe	er (A9h) 4	3	2	1	0
SADDR - S	lave Addre	ess Registe	er (A9h) 4	3	2	1	0

Not bit addressable



Exit from power-down by reset redefines all the SFRs, exit from power-down by external interrupt does no affect the SFRs.

Exit from power-down by either reset or external interrupt does not affect the internal RAM content.

Note: If idle mode is activated with power-down mode (IDL and PD bits set), the exit sequence is unchanged, when execution is vectored to interrupt, PD and IDL bits are cleared and idle mode is not entered.

Mode	Program Memory	ALE	PSEN	PORT0	PORT1	PORT2	PORT3
Idle	Internal	1	1	Port Data ⁽¹⁾	Port Data	Port Data	Port Data
Idle	External	1	1	Floating	Port Data	Address	Port Data
Power Down	Internal	0	0	Port Data ⁽¹⁾	Port Data	Port Data	Port Data
Power Down	External	0	0	Floating	Port Data	Port Data	Port Data

Table 15. The State of Ports During Idle and Power-down Modes

Note: 1. Port 0 can force a "zero" level. A "one" will leave port floating.





Reduced EMI Mode

The ALE signal is used to demultiplex address and data buses on port 0 when used with external program or data memory. Nevertheless, during internal code execution, ALE signal is still generated. In order to reduce EMI, ALE signal can be disabled by setting AO bit.

The AO bit is located in AUXR register at bit location 0. As soon as AO is set, ALE is no longer output but remains active during MOVX and MOVC instructions and external fetches. During ALE disabling, ALE pin is weakly pulled high.

Table 18. AUXR Register

AUXR - Auxiliary Register (8Eh)

7	6	5	4	3	2	1	0
-	-	-	-	-	-	-	AO
Bit Number	Bit Mnemonic	Description					
7	-	Reserved The value re	ad from this b	it is indetermi	nate. Do not s	et this bit.	
6	-	Reserved The value re	ad from this b	it is indetermi	nate. Do not s	et this bit.	
5	-	Reserved The value re	ad from this b	it is indetermi	nate. Do not s	et this bit.	
4	-	Reserved The value re	ad from this b	it is indetermi	nate. Do not s	et this bit.	
3	-	Reserved The value re	ad from this b	it is indetermi	nate. Do not s	et this bit.	
2	-	Reserved The value re	Reserved The value read from this bit is indeterminate. Do not set this bit.				
1	-	Reserved The value re	Reserved The value read from this bit is indeterminate. Do not set this bit.				
0	AO		ore ALE opera	ation during in on during inte			

Reset Value = XXXX XXX0b Not bit addressable 12,000 μ W/cm² rating for 30 minutes, at a distance of about 25 mm, should be sufficient. An exposure of 1 hour is recommended with most of standard erasers.

Erasure of the EPROM begins to occur when the chip is exposed to light with wavelength shorter than approximately 4,000 Å. Since sunlight and fluorescent lighting have wavelengths in this range, exposure to these light sources over an extended time (about 1 week in sunlight, or 3 years in room-level fluorescent lighting) could cause inadvertent erasure. If an application subjects the device to this type of exposure, it is suggested that an opaque label be placed over the window.

Signature Bytes The TS80/87C52X2 has four signature bytes in location 30h, 31h, 60h and 61h. To read these bytes follow the procedure for EPROM verify but activate the control lines provided in Table 31. for Read Signature Bytes. Table 35. shows the content of the signature byte for the TS80/87C52X2.

Location	Contents	Comment
30h	58h	Manufacturer Code: Atmel
31h	57h	Family Code: C51 X2
60h	2Dh	Product name: TS80C52X2
60h	ADh	Product name:TS87C52X2
60h	20h	Product name: TS80C32X2
61h	FFh	Product revision number

Table 21. Signature Bytes Content



TS8xCx2X2

Table 22. DC Parameters in Standard Voltage (Continued	Table 22.	eters in Standard Voltage (Continued)
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Symbol	Parameter	Min	Тур	Мах	Unit	Test Conditions
V _{OH}	Output High Voltage, ports 1, 2, 3	V _{CC} - 0.3 V _{CC} - 0.7 V _{CC} - 1.5			V V V	I _{OH} = -10 μA I _{OH} = -30 μA I _{OH} = -60 μA V _{CC} = 5V ± 10%
V _{OH1}	Output High Voltage, port 0	V _{CC} - 0.3 V _{CC} - 0.7 V _{CC} - 1.5			V V V	I _{OH} = -200 μA I _{OH} = -3.2 mA I _{OH} = -7.0 mA V _{CC} = 5V ± 10%
V _{OH2}	Output High Voltage,ALE, PSEN	V _{CC} - 0.3 V _{CC} - 0.7 V _{CC} - 1.5			V V V	I_{OH} = -100 µA I_{OH} = -1.6 mA I_{OH} = -3.5 mA V_{CC} = 5V ± 10%
R _{RST}	RST Pulldown Resistor	50	90 ⁽⁵⁾	200	kΩ	
I _{IL}	Logical 0 Input Current ports 1, 2 and 3			-50	μΑ	Vin = 0.45V
ILI	Input Leakage Current			±10	μΑ	$0.45V < Vin < V_{CC}$
I _{TL}	Logical 1 to 0 Transition Current, ports 1, 2, 3			-650	μΑ	Vin = 2.0 V
C _{IO}	Capacitance of I/O Buffer			10	pF	Fc = 1 MHz TA = 25°C
I _{PD}	Power Down Current		20 (5)	50	μΑ	$2.0 \ {\rm V} < {\rm V_{CC}}_< 5.5 {\rm V}^{(3)}$
I _{CC} under RESET	Power Supply Current Maximum values, X1 mode: (7)			1 + 0.4 Freq (MHz) at12MHz 5.8 at16MHz 7.4	mA	$V_{\rm CC} = 5.5 V^{(1)}$
I _{CC} operating	Power Supply Current Maximum values, X1 mode: (7)			3 + 0.6 Freq (MHz) at12MHz 10.2 at16MHz 12.6	mA	$V_{CC} = 5.5 V^{(8)}$
l _{cc} idle	Power Supply Current Maximum values, X1 mode: (7)			0.25+0.3 Freq (MHz) at12MHz 3.9 at16MHz 5.1	mA	$V_{\rm CC} = 5.5 V^{(2)}$





Table 23. DC Parameters for Low Voltage

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V _{IL}	Input Low Voltage	-0.5		0.2 V _{CC} - 0.1	V	
V _{IH}	Input High Voltage except XTAL1, RST	0.2 V _{CC} + 0.9		V _{CC} + 0.5	V	
V _{IH1}	Input High Voltage, XTAL1, RST	0.7 V _{CC}		V _{CC} + 0.5	V	
V _{OL}	Output Low Voltage, ports 1, 2, 3 (6)			0.45	V	I _{OL} = 0.8 mA ⁽⁴⁾
V _{OL1}	Output Low Voltage, port 0, ALE, PSEN (6)			0.45	V	I _{OL} = 1.6 mA ⁽⁴⁾
V _{OH}	Output High Voltage, ports 1, 2, 3	0.9 V _{CC}			V	I _{OH} = -10 μA
V _{OH1}	Output High Voltage, port 0, ALE, PSEN	0.9 V _{CC}			V	I _{OH} = -40 μA
I _{IL}	Logical 0 Input Current ports 1, 2 and 3			-50	μA	Vin = 0.45V
ILI	Input Leakage Current			±10	μA	$0.45V < Vin < V_{CC}$
I _{TL}	Logical 1 to 0 Transition Current, ports 1, 2, 3			-650	μA	Vin = 2.0 V
R _{RST}	RST Pulldown Resistor	50	90 ⁽⁵⁾	200	kΩ	
CIO	Capacitance of I/O Buffer			10	pF	Fc = 1 MHz T _A = 25°C
I _{PD}	Power Down Current		20 ⁽⁵⁾ 10 ⁽⁵⁾	50 30	μA	$V_{CC} = 2.0 \text{ V to } 5.5 \text{V}^{(3)}$ $V_{CC} = 2.0 \text{ V to } 3.3 \text{ V}^{(3)}$
I _{cc} under RESET	Power Supply Current Maximum values, X1 mode: ⁽⁷⁾			1 + 0.2 Freq (MHz) at12MHz 3.4 at16MHz 4.2	mA	$V_{CC} = 3.3 V^{(1)}$
I _{CC} operating	Power Supply Current Maximum values, X1 mode: ⁽⁷⁾			1 + 0.3 Freq (MHz) at12MHz 4.6 at16MHz 5.8	mA	V _{CC} = 3.3 V ⁽⁸⁾
I _{CC} idle	Power Supply Current Maximum values, X1 mode: ⁽⁷⁾			0.15 Freq (MHz) + 0.2 at12MHz 2 at16MHz 2.6	mA	V _{CC} = 3.3 V ⁽²⁾

Notes: 1. I_{CC} under reset is measured with all output pins disconnected; XTAL1 driven with T_{CLCH}, T_{CHCL} = 5 ns (see Figure 17.), V_{IL} = V_{SS} + 0.5V,

 $V_{IH} = V_{CC} - 0.5V$; XTAL2 N.C.; $\overline{EA} = RST = Port 0 = V_{CC}$. I_{CC} would be slightly higher if a crystal oscillator used..

2. Idle I_{CC} is measured with all out<u>put</u> pins disconnected; XTAL1 driven with T_{CLCH} , $T_{CHCL} = 5$ ns, $V_{IL} = V_{SS} + 0.5V$, $V_{IH} = V_{CC} - 0.5V$; XTAL2 N.C; Port 0 = V_{CC} ; EA = RST = V_{SS} (see Figure 15.).

Power Down I_{CC} is measured with all output pins disconnected; EA = V_{SS}, PORT 0 = V_{CC}; XTAL2 NC.; RST = V_{SS} (see Figure 16.).

4. Capacitance loading on Ports 0 and 2 may cause spurious noise pulses to be superimposed on the V_{OL}s of ALE and Ports 1 and 3. The noise is due to external bus capacitance discharging into the Port 0 and Port 2 pins when these pins make 1 to 0 transitions during bus operation. In the worst cases (capacitive loading 100pF), the noise pulse on the ALE line may exceed 0.45V with maxi V_{OL} peak 0.6V. A Schmitt Trigger use is not necessary.

5. Typicals are based on a limited number of samples and are not guaranteed. The values listed are at room temperature and 5V.

 Under steady state (non-transient) conditions, I_{OL} must be externally limited as follows: Maximum I_{OL} per port pin: 10 mA Maximum I_{OL} per 8-bit port:

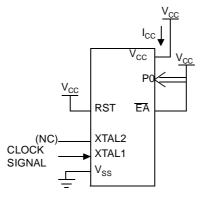
TS8xCx2X2

Port 0: 26 mA Ports 1, 2 and 3: 15 mA Maximum total I_{OL} for all output pins: 71 mA If I_{OL} exceeds the test condition, V_{OL} may exceed the related specification. Pins are not guaranteed to sink current greater than the listed test conditions.

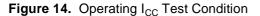
- 7. For other values, please contact your sales office.
- Operating I_{CC} is measured with all output pins disconnected; XTAL1 driven with T_{CLCH}, T_{CHCL} = 5 ns (see Figure 17.), V_{IL} = V_{SS} + 0.5V,

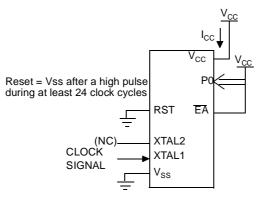
 $V_{IH} = V_{CC} - 0.5V$; XTAL2 N.C.; $\overline{EA} = Port 0 = V_{CC}$; RST = V_{SS} . The internal ROM runs the code 80 FE (label: SJMP label). I_{CC} would be slightly higher if a crystal oscillator is used. Measurements are made with OTP products when possible, which is the worst case.

Figure 13. I_{CC} Test Condition, under reset



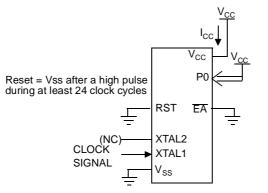
All other pins are disconnected.





All other pins are disconnected.

Figure 15. I_{CC} Test Condition, Idle Mode



All other pins are disconnected.





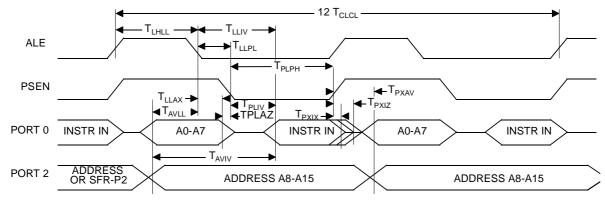
Speed		M MHz	X2 n 30 l 60 l	V node MHz MHz uiv.	stan mod	V dard le 40 Hz	X2 n 20 l 40 l	L node MHz MHz uiv.	stan mo	L dard ode MHz	Units
Symbol	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Т	25		33		25		50		33		ns
T _{LHLL}	40		25		42		35		52		ns
T _{AVLL}	10		4		12		5		13		ns
T _{LLAX}	10		4		12		5		13		ns
T _{LLIV}		70		45		78		65		98	ns
T _{LLPL}	15		9		17		10		18		ns
T _{PLPH}	55		35		60		50		75		ns
T _{PLIV}		35		25		50		30		55	ns
T _{PXIX}	0		0		0		0		0		ns
T _{PXIZ}		18		12		20		10		18	ns
T _{AVIV}		85		53		95		80		122	ns
T _{PLAZ}		10		10		10		10		10	ns

Table 28. AC Parameters for a Variable Clock: derating formula

Symbol	Туре	Standard Clock	X2 Clock	-М	-V	-L	Units
T _{LHLL}	Min	2 T - x	T - x	10	8	15	ns
T _{AVLL}	Min	T - x	0.5 T - x	15	13	20	ns
T _{LLAX}	Min	T - x	0.5 T - x	15	13	20	ns
T _{LLIV}	Max	4 T - x	2 T - x	30	22	35	ns
T _{LLPL}	Min	T - x	0.5 T - x	10	8	15	ns
T _{PLPH}	Min	3 T - x	1.5 T - x	20	15	25	ns
T _{PLIV}	Max	3 T - x	1.5 T - x	40	25	45	ns
T _{PXIX}	Min	х	х	0	0	0	ns
T _{PXIZ}	Max	T - x	0.5 T - x	7	5	15	ns
T _{AVIV}	Max	5 T - x	2.5 T - x	40	30	45	ns
T _{PLAZ}	Max	х	х	10	10	10	ns

External Program Memory Read Cycle

Figure 18. External Program Memory Read Cycle



External Data Memory Characteristics

 Table 29.
 Symbol Description

Symbol	Parameter
T _{RLRH}	RD Pulse Width
T _{WLWH}	WR Pulse Width
T _{RLDV}	RD to Valid Data In
T _{RHDX}	Data Hold After RD
T _{RHDZ}	Data Float After RD
T _{LLDV}	ALE to Valid Data In
T _{AVDV}	Address to Valid Data In
T _{LLWL}	ALE to WR or RD
T _{AVWL}	Address to WR or RD
T _{QVWX}	Data Valid to WR Transition
T _{QVWH}	Data set-up to WR High
T _{WHQX}	Data Hold After WR
T _{RLAZ}	RD Low to Address Float
T _{WHLH}	RD or WR High to ALE high





External Data Memory Read Cycle

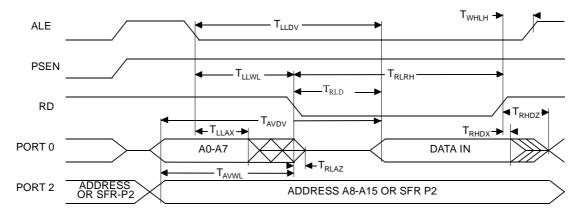


Figure 20. External Data Memory Read Cycle

Serial Port Timing - Shift Register Mode

Table 32. Symbol Description

Symbol	Parameter
T _{XLXL}	Serial port clock cycle time
T _{QVHX}	Output data set-up to clock rising edge
T _{XHQX}	Output data hold after clock rising edge
T _{XHDX}	Input data hold after clock rising edge
T _{XHDV}	Clock rising edge to input data valid

Speed	-I 40 I	M MHz		ИНz	stan mod	V dard le 40 Hz		node MHz MHz	stan mo	L dard ode MHz	Units
Symbol	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
T _{XLXL}	300		200		300		300		400		ns
T _{QVHX}	200		117		200		200		283		ns
T _{XHQX}	30		13		30		30		47		ns
T _{XHDX}	0		0		0		0		0		ns
T_{XHDV}		117		34		117		117		200	ns



EPROM Programming and Verification Characteristics

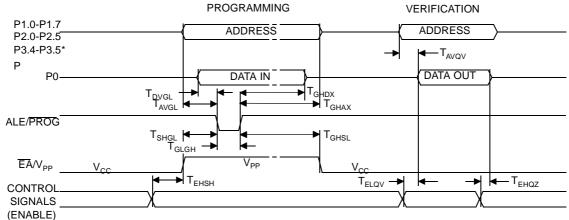
 T_A = 21°C to 27°C; V_{SS} = 0V; $~V_{CC}$ = 5V \pm 10% while programming. V_{CC} = operating range while verifying.

 Table 35.
 EPROM Programming Parameters

Symbol	Parameter	Min	Мах	Units
V _{PP}	Programming Supply Voltage	12.5	13	V
I _{PP}	Programming Supply Current		75	mA
1/T _{CLCL}	Oscillator Frquency	4	6	MHz
T _{AVGL}	Address Setup to PROG Low	48 T _{CLCL}		
T _{GHAX}	Adress Hold after PROG	48 T _{CLCL}		
T _{DVGL}	Data Setup to PROG Low	48 T _{CLCL}		
T _{GHDX}	Data Hold after PROG	48 T _{CLCL}		
T _{EHSH}	(Enable) High to V _{PP}	48 T _{CLCL}		
T _{SHGL}	V _{PP} Setup to PROG Low	10		μs
T _{GHSL}	V _{PP} Hold after PROG	10		μs
T _{GLGH}	PROG Width	90	110	μs
T _{AVQV}	Address to Valid Data		48 T _{CLCL}	
T _{ELQV}	ENABLE Low to Data Valid		48 T _{CLCL}	
T _{EHQZ}	Data Float after ENABLE	0	48 T _{CLCL}	

EPROM Programming and Verification Waveforms

Figure 22. EPROM Programming and Verification Waveforms



* 8KB: up to P2.4, 16KB: up to P2.5, 32KB: up to P3.4, 64KB: up to P3.5



Table 37. Possible Ordering Entries (Continued)

Part Number ⁽³⁾	Memory Size	Supply Voltage	Temperature Range	Max Frequency	Package	Packing
AT80C32X2-RLTUL	ROMLess	2.7 to 5.5V	Industrial & Green	30 MHz ⁽¹⁾	VQFP44	Tray
AT80C32X2-3CSUV	ROMLess	5V ±10%	Industrial & Green	60 MHz ⁽³⁾	PDIL40	Stick
AT80C32X2-SLSUV	ROMLess	5V ±10%	Industrial & Green	60 MHz ⁽³⁾	PLCC44	Stick
AT80C32X2-RLTUV	ROMLess	5V ±10%	Industrial & Green	60 MHz ⁽³⁾	VQFP44	Tray
TS80C52X2zzz-MCA	8K ROM	2.7 to 5.5V	Commercial	40 MHz ⁽¹⁾	PDIL40	Stick
TS80C52X2zzz-MCB	8K ROM	2.7 to 5.5V	Commercial	40 MHz ⁽¹⁾	PLCC44	Stick
TS80C52X2zzz-MCC	8K ROM	2.7 to 5.5V	Commercial	40 MHz ⁽¹⁾	PQFP44	Tray
TS80C52X2zzz-MCE	8K ROM	2.7 to 5.5V	Commercial	40 MHz ⁽¹⁾	VQFP44	Tray
TS80C52X2zzz-LCA	8K ROM	2.7 to 5.5V	Commercial	30 MHz ⁽¹⁾	PDIL40	Stick
TS80C52X2zzz-LCB	8K ROM	2.7 to 5.5V	Commercial	30 MHz ⁽¹⁾	PLCC44	Stick
TS80C52X2zzz-LCC	8K ROM	2.7 to 5.5V	Commercial	30 MHz ⁽¹⁾	PQFP44	Tray
TS80C52X2zzz-LCE	8K ROM	2.7 to 5.5V	Commercial	30 MHz ⁽¹⁾	VQFP44	Tray
TS80C52X2zzz-VCA	8K ROM	5V <u>±</u> 10%	Commercial	60 MHz ⁽³⁾	PDIL40	Stick
TS80C52X2zzz-VCB	8K ROM	5V ±10%	Commercial	60 MHz ⁽³⁾	PLCC44	Stick
TS80C52X2zzz-VCC	8K ROM	5V ±10%	Commercial	60 MHz ⁽³⁾	PQFP44	Tray
TS80C52X2zzz-VCE	8K ROM	5V ±10%	Commercial	60 MHz ⁽³⁾	VQFP44	Tray
TS80C52X2zzz-MIA	8K ROM	5V ±10%	Industrial	40 MHz ⁽¹⁾	PDIL40	Stick
TS80C52X2zzz-MIB	8K ROM	5V ±10%	Industrial	40 MHz ⁽¹⁾	PLCC44	Stick
TS80C52X2zzz-MIC	8K ROM	5V ±10%	Industrial	40 MHz ⁽¹⁾	PQFP44	Tray
TS80C52X2zzz-MIE	8K ROM	5V ±10%	Industrial	40 MHz ⁽¹⁾	VQFP44	Tray
TS80C52X2zzz-LIA	8K ROM	2.7 to 5.5V	Industrial	30 MHz ⁽¹⁾	PDIL40	Stick
TS80C52X2zzz-LIB	8K ROM	2.7 to 5.5V	Industrial	30 MHz ⁽¹⁾	PLCC44	Stick
TS80C52X2zzz-LIC	8K ROM	2.7 to 5.5V	Industrial	30 MHz ⁽¹⁾	PQFP44	Tray
TS80C52X2zzz-LIE	8K ROM	2.7 to 5.5V	Industrial	30 MHz ⁽¹⁾	VQFP44	Tray
TS80C52X2zzz-VIA	8K ROM	5V ±10%	Industrial	60 MHz ⁽³⁾	PDIL40	Stick
TS80C52X2zzz-VIB	8K ROM	5V ±10%	Industrial	60 MHz ⁽³⁾	PLCC44	Stick
TS80C52X2zzz-VIC	8K ROM	5V ±10%	Industrial	60 MHz ⁽³⁾	PQFP44	Tray
TS80C52X2zzz-VIE	8K ROM	5V ±10%	Industrial	60 MHz ⁽³⁾	VQFP44	Tray
AT80C52X2zzz-3CSUM	8K ROM	5V ±10%	Industrial & Green	40 MHz ⁽¹⁾	PDIL40	Stick
AT80C52X2zzz-SLSUM	8K ROM	5V ±10%	Industrial & Green	40 MHz ⁽¹⁾	PLCC44	Stick
AT80C52X2zzz-RLTUM	8K ROM	5V ±10%	Industrial & Green	40 MHz ⁽¹⁾	VQFP44	Tray